NSN 5961-01-333-4930

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Inclosure	Material:
mologuic	material.

Metal

Overall Length:

0.190 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.219 inches

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-18

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Features Provided:

Hermetically sealed case and electrostatic sensitive

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

30.0 breakdown voltage, dc

Current Rating Per Characteristic:

10.00 nanoamperes reverse gate current with all other terminals short-circuit to source, junction-gate

Power Rating Per Characteristic:

135.0 milliwatts total power dissipation

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0